

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L7	61005	(Ta2O5 or (Ta?sub\$3 adj O?sub\$3) or ((tantalum or Ta) near5 (oxide or pentaethoxy)) or (high adj k) or SiN or Si3N4 or (Si?sub\$3 adj N?sub\$3) or ((Si or silicon) adj nitride) or (barium adj strontium adj titanate) or (strontium adj titanate) or (lead adj zirconium adj titanate) or (strontium adj bismuth adj tantalate) or (Sr?sub\$5 near4 Ba?sub\$5 near4 Ti near4 O?sub\$5) or SrTiO3 or SrTiO?sub\$3 or PbZrTiO3 or PbTiO?sub\$3 or (Sr?sub\$5 near4 Bi?sub\$5 near4 Ta?sub\$5 near4 O?sub\$5)) and (densif\$6 or stabil\$6)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/08 19:11
L8	10419	7 and ((oxydi\$6 or oxida\$6 or oxid\$6) same (wet or steam or moist\$6 or water or vapor or H2O or (H?sub\$2 adj O)))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/08 19:09
L9	31830	7 and (@ad<"19990422" or @rlad<"19990422")	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/08 19:12
L10	3031	8 and 9 and semiconductor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/08 19:08
L11	6408	7 and ((oxydi\$6 or oxida\$6 or oxid\$6) with (wet or steam or moist\$6 or water or vapor or H2O or (H?sub\$2 adj O)))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/08 19:10
L12	1850	11 and 10	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/08 19:10

L13	8777	(Ta2O5 or (Ta?sub\$3 adj O?sub\$3) or ((tantalum or Ta) near5 (oxide or pentaethoxy)) or (high adj k) or SiN or Si3N4 or (Si?sub\$3 adj N?sub\$3) or ((Si or silicon) adj nitride) or (barium adj strontium adj titanate) or (strontium adj titanate) or (lead adj zirconium adj titanate) or (strontium adj bismuth adj tantalate) or (Sr?sub\$5 near4 Ba?sub\$5 near4 Ti near4 O?sub\$5) or SrTiO3 or SrTiO?sub\$3 or PbZrTiO3 or PbTiO?sub\$3 or (Sr?sub\$5 near4 Bi?sub\$5 near4 Ta?sub\$5 near4 O?sub\$5)) same (densif\$6 or stabil\$6)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/08 19:12
L14	10872	(Ta2O5 or (Ta?sub\$3 adj O?sub\$3) or ((tantalum or Ta) near5 (oxide or pentaethoxy)) or (high adj k) or SiN or Si3N4 or (Si?sub\$3 adj N?sub\$3) or ((Si or silicon) adj nitride) or (barium adj strontium adj titanate) or (strontium adj titanate) or (lead adj zirconium adj titanate) or (strontium adj bismuth adj tantalate) or (Sr?sub\$5 near4 Ba?sub\$5 near4 Ti near4 O?sub\$5) or SrTiO3 or SrTiO?sub\$3 or PbZrTiO3 or PbTiO?sub\$3 or (Sr?sub\$5 near4 Bi?sub\$5 near4 Ta?sub\$5 near4 O?sub\$5)) same ((oxydi\$6 or oxida\$6 or oxidii\$6) same (wet or steam or moist\$6 or water or vapor or H2O or (H?sub\$2 adj O)))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/08 19:11
L15	625	13 and 14 and semiconductor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/08 19:12
L16	310	15 and (@ad<"19990422" or @rlad<"19990422")	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/08 19:12